NSN 5962-01-357-5595

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view Online at https://aerobasegroup.com/hsh/5962-01-557-5595
Overall Length:
Between 0.675 inches and 0.700 inches
Overall Height:
Between 0.085 inches and 0.190 inches
Overall Width:
Between 0.675 inches and 0.700 inches
Body Length:
Between 0.640 inches and 0.660 inches
Body Width:
Between 0.640 inches and 0.660 inches
Body Height:
Between 0.075 inches and 0.155 inches
Maximum Power Dissipation Rating:
750.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bidirectional and electrostatic sensitive and high reliability and monolithic and asynchronous and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leaded chip carrier
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
38 input
Current Rating Per Characteristic:
150.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-2.0 volts power source and 7.0 volts power source
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
44 pin
Shelf Life:

N/a

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Demilitarization:

No

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